



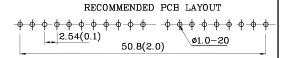
12 SEGMENT BAR GRAPH ARRAY

Features

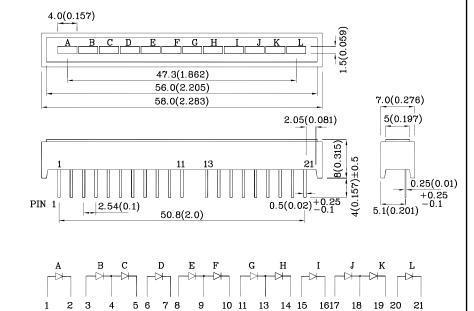
- Robust package
- Uniform light disbursement
- Ideal for backlighting logos or icons
- Excellent for flush mounting
- \bullet Standard configuration: Black face w/ white segments
- RoHS compliant







Package Schematics



Notes:

1. All dimensions are in millimeters (inches), Tolerance is $\pm 0.25 (0.01")$ unless otherwise noted.

12 NO PIN

2. Specifications are subject to change without notice.

	UR (GaAsP/GaP)	Unit		
Reverse Voltage	V_{R}	5	V	
Forward Current	I_{F}	30	mA	
Forward Current (Peak) 1/10 Duty Cycle 0.1ms Pulse Width	ifs	160	mA	
Power Dissipation	P_D	75	mW	
Operating Temperature	T_{A}	-40 ~ +85	°C	
Storage Temperature	Tstg	-40 ~ +85		
Lead Solder Temperature [2mm Below Package Base]				

Operating Characteristics (T _A =25°C)		UR (GaAsP/GaP)	Unit
Forward Voltage (Typ.) (I _F =10mA)	V_{F}	1.9	V
Forward Voltage (Max.) (I _F =10mA)	V_{F}	2.5	V
Reverse Current (Max.) $(V_R=5V)$	$I_{ m R}$	10	uA
Wavelength of Peak Emission CIE127-2007* (Typ.) (I _F =10mA)	λΡ	627*	nm
Wavelength of Dominant Emission CIE127-2007* (Typ.) $(I_F=10\text{mA})$	λD	617*	nm
Spectral Line Full Width At Half-Maximum (Typ.) (I _F =10mA)	$\triangle \lambda$	45	nm
Capacitance (Typ.) (V _F =0V, f=1MHz)	C	15	pF

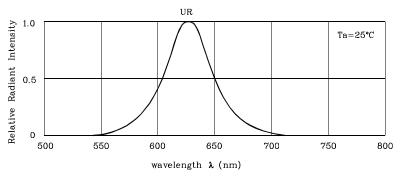
Part Number	Emitting Color	Emitting Material	Luminous I CIE127- (I _F =10m/	2007*	Wavelength CIE127-2007* nm λP	Description
			min.	typ.		
XHURX12DWB	Red	GaAsP/GaP	5600 1400*	10990 3490*	627*	12 Segments Bar graph-Display

^{*}Luminous intensity value and wavelength are in accordance with CIE127-2007 Mar 05.2014

XDSA1924 V7-X Layout: Maggie L.

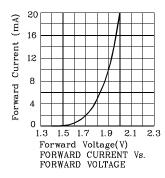


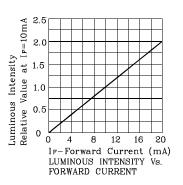


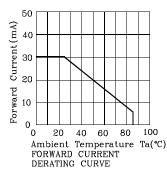


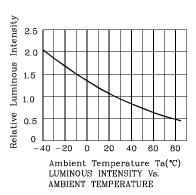
RELATIVE INTENSITY Vs. CIE WAVELENGTH

❖ UR

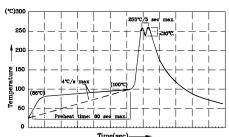








Wave Soldering Profile for Thru-Hole Products (Pb-Free Components)



- nmend pre-heat temperature of 105°C or less (as measured with a noccouple attached to the LED pins) prior to immersion in the solder with a maximum solder bath temperature of 250°C wave soldering temperature between 245°C \sim 255°C for 3 sec (5 sec
- 2.Peak wave soldering temperature between 240 to 7 250 to 1 3 50 to 1 apply stress to the epoxy resin while the temperature is abd. 4.Pixtures should not incur stress on the component when mounting during soldering process.
 5.SAC 305 solder alloy is recommended.
 6.No more than one wave soldering pass.

Remarks:

If special sorting is required (e.g. binning based on forward voltage, luminous intensity / luminous flux, or wavelength),

the typical accuracy of the sorting process is as follows:

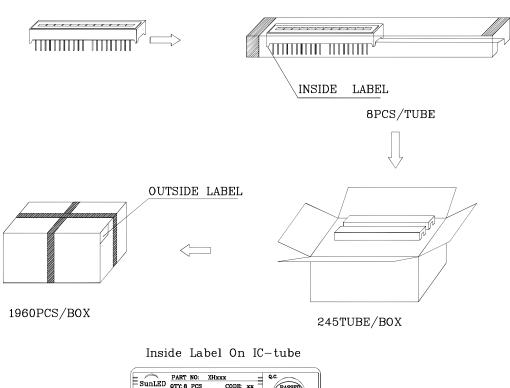
- 1. Wavelength: +/-1nm
- 2. Luminous Intensity / Luminous Flux: +/-15%
- 3. Forward Voltage: +/-0.1V

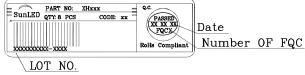
Note: Accuracy may depend on the sorting parameters.



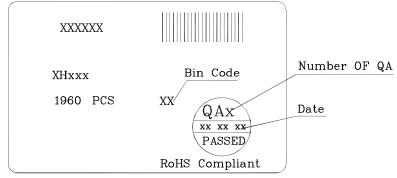


PACKING & LABEL SPECIFICATIONS





Outside Label On Box



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